

Contents

| | | |
|----------|--|-----------|
| 1 | Introduction and Background. | 1 |
| 1.1 | Introduction | 1 |
| 1.1.1 | Silicon | 1 |
| 1.1.2 | Transition Metals in Silicon | 2 |
| 1.1.3 | Isotopically Enriched Silicon | 3 |
| 1.1.4 | The Experiment | 3 |
| 1.2 | Bound Excitons | 4 |
| 1.3 | Isoelectronic Bound Excitons | 5 |
| 1.3.1 | IBE Binding Mechanism | 7 |
| 1.3.2 | Characteristic Properties of Isoelectronic Bound Excitons | 9 |
| 1.3.3 | Electronic Levels of Isoelectronic Bound Excitons Centres | 10 |
| 1.4 | Isotope Effects | 11 |
| 1.4.1 | Host Isotope Effects | 11 |
| 1.4.2 | Impurity Isotope Shift | 13 |
| 1.5 | Local Vibrational Mode Replicas | 15 |
| 1.5.1 | Isotope Effects on Vibrational Mode Replicas | 16 |
| 1.6 | Transition Metals in Si | 17 |
| 1.6.1 | Effect of Transition Metals on Si | 18 |
| 1.6.2 | Solubility of Cu in Si | 20 |
| 1.6.3 | Diffusivity of Cu in Si | 21 |
| | References | 23 |
| 2 | History of the Observed Centres in Silicon | 29 |
| 2.1 | The 1014 meV “Cu-pair”: The Cu ₄ Centre | 29 |
| 2.2 | The 944 meV “Perturbed Cu-pair”: The Cu ₃ Ag Centre | 35 |
| 2.3 | The 778 meV “Single Ag”: The Ag ₄ Centre | 37 |
| 2.4 | The 735 meV “Fe, or Au-Fe pair”: The Cu ₃ Au Centre | 38 |
| 2.5 | The 1066 meV “FeB pair”: The Cu ₄ Au Centre | 39 |

| | | |
|----------|---|----|
| 2.6 | The 777 meV Cu_4Pt and the 884 meV Cu_3Pt Centres | 40 |
| 2.7 | The 968 meV S_A and 812 meV S_B Centres | 41 |
| 2.8 | The 1044 meV “Q Line”: The $\text{Li}_4 \text{V}_\text{Si}$ Centre | 42 |
| | References | 42 |
| 3 | Experimental Method. | 47 |
| 3.1 | Silicon Samples. | 47 |
| 3.1.1 | Sample Preparation | 47 |
| 3.1.2 | Cu Diffusion | 50 |
| 3.1.3 | Au and Pt Ion Implantation | 51 |
| 3.2 | Fourier Transform Spectroscopy | 52 |
| 3.3 | Experimental Setup | 55 |
| 3.3.1 | Fourier Transform Spectrometer | 55 |
| 3.3.2 | Cryostat | 56 |
| 3.3.3 | Other Experimental Methods | 56 |
| | References | 57 |
| 4 | Results. | 59 |
| 4.1 | Cu and Ag-Related Centres | 59 |
| 4.1.1 | The 1014 meV Cu_4 Complex | 62 |
| 4.1.2 | The 944 meV Cu_3Ag Complex | 62 |
| 4.1.3 | The 867 meV Cu_2Ag_2 Complex | 63 |
| 4.1.4 | The 778 meV Ag_4 Complex | 65 |
| 4.1.5 | The CuLi_2Ag Complex | 66 |
| 4.2 | Au-Related Centres | 67 |
| 4.2.1 | The 735 meV Cu_3Au Complex | 67 |
| 4.2.2 | Four-Atom $(\text{Cu}, \text{Li})_3\text{Au}$ Complexes | 68 |
| 4.2.3 | The 1066 meV Cu_4Au Complex | 70 |
| 4.2.4 | Five-Atom $(\text{Cu}, \text{Li})_4\text{Au}$ Complexes | 72 |
| 4.3 | Pt-Related Centres | 72 |
| 4.3.1 | The 777 meV Cu_4Pt Complex | 75 |
| 4.3.2 | The 884 meV Cu_3Pt Complex | 77 |
| 4.3.3 | Four-Atom $(\text{Cu}, \text{Li})_3\text{Pt}$ Complexes | 78 |
| 4.3.4 | Five-Atom $(\text{Cu}, \text{Li})_4\text{Pt}$ Complexes | 79 |
| 4.4 | S-Related Centres | 83 |
| 4.4.1 | The 812 meV S_B Complex | 83 |
| | References | 85 |
| 5 | Discussion and Conclusion | 87 |
| 5.1 | Discussion of Experimental Results | 87 |
| 5.2 | Conclusion | 89 |
| | References | 90 |
| | Curriculum Vitae | 93 |

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